

Dual Low-Drop Voltage Regulator

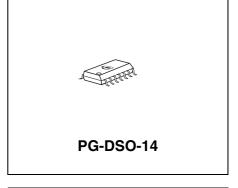
TLE 4470

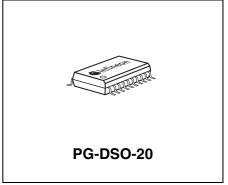




Features

- Stand-by output 180 mA; 5 V \pm 2%
- Adjustable reset switching threshold
- Main output 350 mA; tracked to the stand-by output
- Low quiescent current consumption in standby mode
- Disable function for main output
- Wide operation range: up to 45 V
- Very low dropout
- Power-On-Reset circuit sensing the stand-by voltage
- Early warning comparator for supply undervoltage
- Output protected against short circuit
- Wide temperature range: -40 °C to 150 °C
- Overtemperature protection
- Overload protection
- Green Product (RoHS compliant)
- AEC Qualified





Functional Description

The TLE 4470 is a monolithic integrated voltage regulator with two very low-drop outputs, a main output Q2 for loads up to 350 mA and a stand by output Q1 providing a maximum of 180 mA. The device is available in two packages the PG-DSO-14 and PG-DSO-20. It is designed to supply microprocessor systems under the severe conditions of automotive applications and is therefore equipped with additional protection functions against overload, short circuit and overtemperature. Of course the TLE 4470 can also be used in other applications where two stabilized voltages are required.

The device operates in the wide junction temperature range of -40 $^{\circ}$ C to 150 $^{\circ}$ C.

The stand-by regulator transforms an input voltage $V_{\rm l}$ in the range of 5.6 V \leq $V_{\rm l} \leq$ 45 V to $V_{\rm Q1,nom}$ = 5 V within an accuracy of 2%, whereas the main regulator is adjustable. By

Туре	Package
TLE 4470 GS	PG-DSO-14
TLE 4470 G	PG-DSO-20

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use of an external voltage divider the main output voltage can be set to $V_{\rm Q2} \ge 5$ V for the TLE 4470 G type (PG-DSO-20 package). $V_{\rm Q1}$ is compared to the voltage at pin ADJ2, which is proportional to the output voltage $V_{\rm Q2}$. A control amplifier drives the base of the series PNP transistor via a buffer.

The main output voltage $V_{\rm O2}$ is tracked to the accuracy of the stand-by output.

For the TLE 4470 GS (PG-DSO-14 package) the output voltage is fixed to 5 V.

To save energy e.g. in battery powered body electronic applications, the main regulator can be switched off via the disable input, which causes the current consumption to drop to $180~\mu\text{A}$ typical.

Two additional features of the TLE 4470 are an early warning comparator (can be used e.g. to monitor the supply voltage $V_{\rm I}$) and reset generator with an adjustable reset delay time. The TLE 4470 G (PG-DSO-20 package) has in addition an adjustable reset switching threshold. This feature is useful with microprocessors which guarantee a safe operation down to voltages below the internally set reset threshold of 4.65 V typical.

Two functions are included in the reset generator, a power-on-reset and an undervoltage reset. The power-on-reset feature is necessary for a defined start of the microprocessor when switching on the application. The reset signal is kept low for a certain delay time after the output voltage $V_{\rm Q1}$ of the regulator has surpassed the reset threshold. An external delay capacitor sets this delay time. The under voltage reset circuit supervises the stand-by output voltage. In case $V_{\rm Q1}$ falls below the reset switching threshold the reset output is set LOW after a short reaction time. The reset LOW signal is generated down to an output voltage $V_{\rm Q1}$ of 1 V.

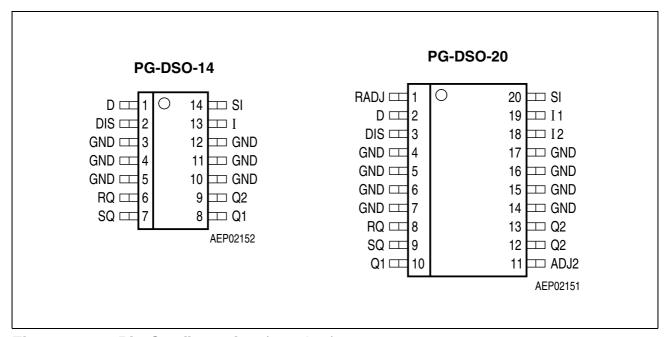


Figure 1 Pin Configuration (top view)



Pin Definitions and Functions

Table 1 PG-DSO-20

Pin No.	Symbol	Function
1	RADJ	Reset switching threshold adjust; for setting the reset switching threshold connect to a voltage divider from Q1 to GND. If this input is connected to GND, the reset is triggered at the internal threshold.
2	D	Reset delay; connect a capacitor $C_{\rm D}$ to GND for delay time adjustment
3	DIS	Disable input main regulator; Q2 disabled with high signal
4, 5, 6, 7	GND	Ground
8	RQ	Reset output; the open collector output is connected to Q1 via an integrated 30 $k\Omega$ resistor
9	SQ	Sense output; the open collector output is connected to Q1 via an integrated 30 $k\Omega$ resistor
10	Q1	Stand-by regulator output voltage; block to GND with a capacitor $C_{\rm Q1} \ge 6~\mu{\rm F}$, ESR < 10 Ω at 10 kHz
11	ADJ2	Main regulator adjust input; Q2 can be set to higher values than 5 V by an external voltage divider from Q2 to GND
12, 13	Q2	Main regulator output voltage ; block to GND with a capacitor $C_{\rm Q2} \ge$ 10 μF, ESR < 10 Ω at 10 kHz
14, 15, 16, 17	GND	Ground
18	12	Main regulator input voltage; block to GND directly at the IC with a ceramic capacitor
19	l1	Stand-by regulator input voltage; block to GND directly at the IC with a ceramic capacitor
20	SI	Sense comparator input
·		



Table 2 PG-DSO-14

Pin No.	Symbol	Function
1	D	Reset delay; connect a capacitor $C_{\rm D}$ to GND for delay time adjustment
2	DIS	Disable input main regulator; Q2 disabled with high signal
3, 4, 5	GND	Ground
6	RQ	Reset output; the open collector output is connected to Q1 via an integrated 30 $k\Omega$ resistor
7	SQ	Sense output; the open collector output is connected to Q1 via an integrated 30 $k\Omega$ resistor
8	Q1	Stand-by regulator output voltage; block to GND with a capacitor, $C_{\rm Q1} \ge 6~\mu \rm F$, ESR < 10 Ω at 10 kHz
9	Q2	Main regulator output voltage ; 5 V output tracking to Q1, block to GND with a capacitor $C_{\rm Q2}$ ≥ 10 μF, ESR < 10 Ω at 10 kHz
10, 11, 12	GND	Ground
13	I	Main and stand-by regulator input voltage; block to GND directly at the IC with a ceramic capacitor
14	SI	Sense comparator input

RADJ: Adjustable reset switching threshold is not available in the PG-DSO-14 package. Reset is always triggered at the internal threshold.

ADJ2: Main regulator adjust input is internally connected to $V_{\rm O2}$.



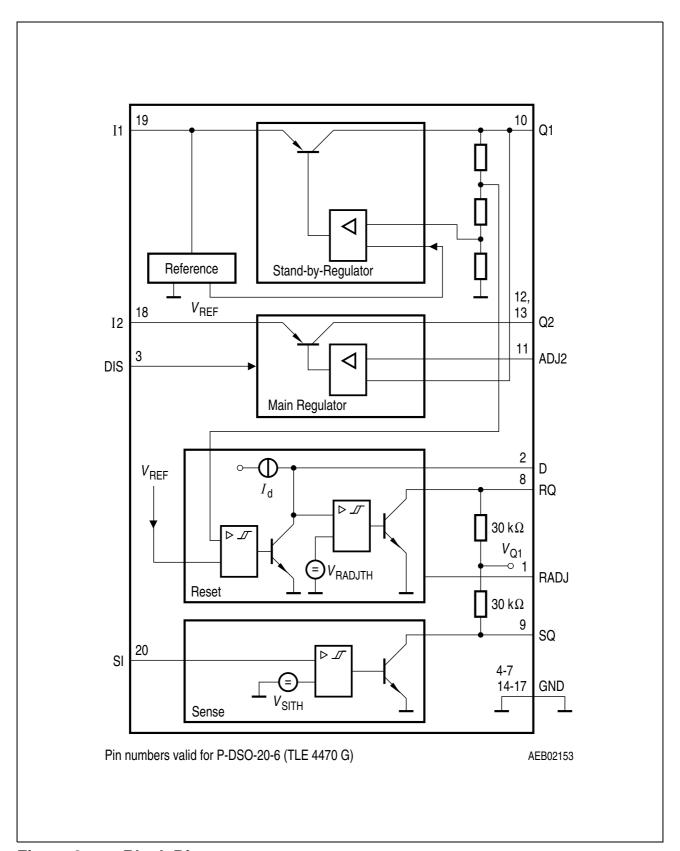


Figure 2 Block Diagram



Table 3 Absolute Maximum Ratings

-40 °C < $T_{\rm j}$ < 150 °C

Parameter	Symbol	Limit	Values	Unit	Remarks
		Min.	Max.		
Stand-by Regulator Inpu	ıt I1	•	-	•	
Voltage	V_{I1}	-42	45	V	_
Current	I_{I1}	_	_	mA	Internally limited
Main Regulator Input I2		•		•	
Voltage	V_{l2}	-42	45	V	_
Current	I_{12}	_	_	mA	Internally limited
Stand-by Output Q1		•		•	
Voltage	V_{Q1}	-1	7	V	_
Current	I_{Q1}	_	_	mA	Internally limited
Main Output Q2		•		•	
Voltage	V_{Q2}	-1	36	V	_
Current	I_{Q2}	_	_	mA	Internally limited
Main Regulator Adjust In	•	•	-	•	
Voltage	V_{ADJ2}	-0.3	18	V	_
Current	I_{ADJ2}	_	_	mA	Internally limited
Sense Output SQ		•		•	
Voltage	$V_{\sf SQ}$	-0.3	25	V	_
Current	I_{SQ}	-5	5	mA	_
Reset Output RQ		•		•	
Voltage	V_{RQ}	-0.3	25	V	_
Current	I_{RQ}	-5	5	mA	_
Disable Input DIS		•		•	
Voltage	V_{DIS}	-42	45	V	_
Current	I_{DIS}	-2	2	mA	_
Sense Input SI	,	•	•		
Voltage	V_{SI}	-25	18	V	_
Current	I_{SI}	-2	2	mA	_



 Table 3
 Absolute Maximum Ratings (cont'd)

-40 $^{\circ}$ C < $T_{\rm j}$ < 150 $^{\circ}$ C

Parameter	Symbol	Limit Values		Unit	Remarks
		Min.	Max.		
Reset Delay D			1	1	
Voltage	V_{D}	-0.3	7	V	_
Current	I_{D}	-2	2	mA	_
Reset Switching Threshold	Adjust RA	DJ	•	•	•
Voltage	V_{RADJ}	-0.3	7	V	_
Current	I_{RADJ}	_	_	mA	Internally limited
Temperatures	•	•	•	•	•
Junction temperature	T_{j}	-50	150	°C	_
Storage temperature	$T_{ m stg}$	-50	150	°C	_

Note: ESD-Protection according to MIL Std. 883: ±2 kV.

Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.

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Table 4 Operating Range

Parameter	Symbol	Limit	Values	Unit	Remarks	
		Min.	Max.			
Stand-by regulator input voltage	V_{I1}	5.6	45	V	-	
Main regulator input voltage	V_{l2}	V _{Q2,nom} + 0.6 V	45	V	-	
Stand-by regulator output current	I_{Q1}	0	180	mA	-	
Main regulator output current	I_{Q2}	0	350	mA	-	
Disable input voltage	V_{DIS}	-0.3	45	V	_	
Sense input voltage	V_{SI}	-0.3	17	V	_	
Junction temperature	T_{j}	-40	150	°C	_	
Thermal Resistances PG-DS	O-14					
Junction pin	$R_{thj\text{-pin}}$	_	32	K/W	Measured to pin 4	
Junction ambient	$R_{\text{thj-a}}$	_	112	K/W	1)	
Thermal Resistances PG-DS				•		
Junction pin	$R_{thj\text{-pin}}$	_	23	K/W	Measured to pin 4	
Junction ambient	R_{thj-a}	_	100	K/W	1)	

¹⁾ Package mounted on PCB $80 \times 80 \times 1.5$ mm³; $35~\mu$ Cu; $5~\mu$ Sn; Footprint only; zero airflow.

Note: In the operating range the functions given in the circuit description are fulfilled.

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 Table 5
 Electrical Characteristics

 $V_{\rm l1}$ = $V_{\rm l2}$ = 14 V; $V_{\rm DIS}$ < $V_{\rm DISL}$; -40 °C < $T_{\rm j}$ < 150 °C; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition
		Min.	Тур.	Max.		
Stand-by Regulator						
Output 1						
Output voltage	V_{Q1}	4.90	5.0	5.10	V	1 mA < I_{Q1} < 100 mA
Output current limitation	I_{Q1}	180	280	_	mA	1)
Output drop voltage; $V_{\text{DRQ1}} = V_{\text{I1}} - V_{\text{Q1}}$	V_{DRQ1}	_	300	500	mV	$I_{\rm Q1} = 100 \ {\rm mA}^{1)}$
Current Consumption	on					
Quiescent current; stand-by	I_{q}	_	180	250	μΑ	$I_{\rm Q1}$ = 300 μ A; $T_{\rm j}$ = 25 °C $V_{\rm DIS}$ > $V_{\rm DISH}$ (Q2 = OFF)
$I_{q} = I_{I1} - I_{Q1}$		_	180	300	μΑ	I_{Q1} = 300 $\mu\mathrm{A}$; V_{DIS} > V_{DISH} (Q2 = OFF)
Quiescent current $I_{q} = I_{l1} - I_{Q1}$	I_{q}	_	4	6	mA	I_{Q1} = 100 mA; V_{DIS} > V_{DISH} (Q2 = OFF)
Regulator Performa	nce					
Load regulation	$\Delta V_{ m Q1,Lo}$	_	15	50	mV	1 mA $< I_{Q1} <$ 150 mA
Load regulation	$\Delta V_{ m Q1,Lo}$	_	5	25	mV	1 mA $< I_{Q1} <$ 100 mA
Line regulation	$\Delta V_{ m Q1,Li}$	_	5	20	mV	$I_{\rm Q1}$ = 1 mA; 6 V < $V_{\rm I1}$ < 28 V
Power Supply Ripple Rejection	PSRR	_	60	_	dB	20 Hz $< f_{\rm r} <$ 20 kHz; $V_{\rm r} =$ 5 Vpp
Temperature output voltage drift	$\Delta V_{ m Q1}/\Delta T$	_	0.3	_	mV/ K	_
dV_{I1}/dt stability	V_{Q1}	4.5	_	5.5	V	no reset occurs ²⁾
Value of output capacitance	C_{Q1}	6	_	_	μF	_
ESR of output capacitance	ESR _{CQ1}	_	_	10	Ω	at 10 kHz



 Table 5
 Electrical Characteristics (cont'd)

 $V_{\rm I1}$ = $V_{\rm I2}$ = 14 V; $V_{\rm DIS}$ < $V_{\rm DISL}$; -40 °C < $T_{\rm j}$ < 150 °C; unless otherwise specified

Parameter Symbol Limit Values		Unit	Test Condition			
		Min.	Тур.	Max.		
Main-Regulator						
Output 2						
Output voltage tracking accuracy	$\Delta V_{\rm Q2} = V_{\rm Q2} - V_{\rm Q1}$	-25	5	25	mV	$ \begin{array}{c} {\rm 5~mA} < I_{\rm Q2} < {\rm 100~mA;} \\ {\rm 6~V} < V_{\rm I2} < {\rm 40~V^{3)}} \end{array} $
Output voltage tracking accuracy	$\Delta V_{\rm Q2} = V_{\rm Q2} - V_{\rm Q1}$	-25	5	25	mV	$\begin{array}{l} \text{5 mA} < I_{\text{Q2}} < \text{250 mA}; \\ \text{7 V} < V_{\text{I2}} < \text{28 V}^{3)} \end{array}$
Adjust input current	I_{ADJ2}	-1	_	1	μΑ	_
Output current limitation	I_{Q2}	350	500	_	mA	1)
Output drop voltage $V_{\text{DRQ2}} = V_{\text{I2}} - V_{\text{Q2}}$	V_{DRQ2}	_	300	600	mV	$I_{\rm Q2}$ = 200 mA ¹⁾
Current Consumption	on					
Quiescent current; $I_{q} = I_{l} - I_{Q}$	I_{q}	_	7	15	mA	$I_{\rm Q2}$ = 200 mA; $I_{\rm Q1}$ = 300 μ A
Quiescent current; $I_q = I_l - I_Q$	I_{q}	_	250	500	μΑ	$I_{\rm Q2} = I_{\rm Q1} = 300 \ \mu \text{A};$ $T_{\rm j} = 25 \ ^{\circ}\text{C}$
Regulator Performa	nce					
Load regulation	$\Delta V_{ m Q2,Lo}$	_	5	25	mV	$5 \text{ mA} < I_{Q2} < 200 \text{ mA};$
Line regulation	$\Delta V_{ m Q2,Li}$	_	5	20	mV	$I_{\rm Q2}$ = 5 mA; 6 V < $V_{\rm I2}$ < 28 V
Power Supply Ripple Rejection	PSRR	_	60	_	dB	20 Hz $< f_{\rm r} <$ 20 kHz; $V_{\rm r} =$ 5 Vpp
Temperature output voltage drift	$\Delta V_{\rm Q2}/\Delta T$	_	0.5	_	mV/ K	_
dV_{12}/dt stability	V_{Q2}	4.5	_	5.5	V	no reset occurs ³⁾
Value of output capacitance	C_{Q2}	10	_	_	μF	_
ESR of output capacitance	ESR _{CQ2}	_	_	10	Ω	at 10 kHz



 Table 5
 Electrical Characteristics (cont'd)

 $V_{\rm l1}$ = $V_{\rm l2}$ = 14 V; $V_{\rm DIS}$ < $V_{\rm DISL}$; -40 °C < $T_{\rm j}$ < 150 °C; unless otherwise specified

Parameter	Symbol	Li	Limit Values			Test Condition	
		Min.	Тур.	Max.			
Disable Input DIS							
H-input voltage threshold	V_{DISH}	2.3	_	_	V	_	
L-input voltage threshold	V_{DISL}	_	_	1.4	V	Output 2 active	
H-input current	I_{DISH}	-2	-1	1	μΑ	$2.3 \text{ V} < V_{\text{DIS}} < 7 \text{ V}$	
L-input current	I_{DISL}	-6	-2	-0.5	μΑ	$0 \text{ V} < V_{\text{DIS}} < 1.4 \text{ V}$	
Reset Timing D and	Output R	Q					
Reset switching threshold	$V_{Q,rt}$	4.5	4.65	4.8	V	RADJ connected to GND	
Reset adjust threshold	V_{RADJTH}	1.25	1.35	1.45	V	$V_{\rm Q1} > 3.5 \text{ V}$	
Reset output low voltage	V_{RQL}	_	0.15	0.3	V	$R_{\rm RQ}$ = 10 k Ω externally connected to Q1; $V_{\rm Q1}$ \geq 1 V	
Reset high voltage	V_{RQH}	4.5	_	_	V	_	
Reset pull-up resistor	R_{RQ}	20	30	45	kΩ	Internally connected to Q1	
Reset charging current	$I_{D,c}$	3	5	9	μΑ	$V_{\rm D}$ = 1 V	
Upper timing threshold	V_{DU}	1.5	1.8	2.2	V	_	
Lower timing threshold	V_{DL}	0.3	0.4	0.55	V	_	
Reset delay time	$t_{\sf rd}$	12	15	20	ms	$C_{\rm D}$ = 47 nF	
Reset reaction time	t_{rr}	_	0.5	2.0	μs	$C_{\rm D} = 47 \; {\rm nF}$	



Table 5 Electrical Characteristics (cont'd)

 $V_{\rm l1}$ = $V_{\rm l2}$ = 14 V; $V_{\rm DIS}$ < $V_{\rm DISL}$; -40 °C < $T_{\rm j}$ < 150 °C; unless otherwise specified

Parameter	Symbol	Li	Limit Values			Test Condition			
		Min.	Тур.	Max.					
Sense Input SI and	Sense Input SI and Output SQ								
Sense threshold voltage	V_{SITH}	1.28	1.35	1.45	V	$V_{ m SI}$ decreasing			
Sense threshold hysteresis	V_{SIHY}	25	60	100	mV	_			
Sense output low voltage	V_{SQL}	_	0.15	0.4	V	$R_{\rm SQ}$ = 10 k Ω externally connected to Q1; $V_{\rm SI}$ < 1.1 V; $V_{\rm I1}$ > 4.5 V			
Sense output high voltage	V_{SQH}	4.5	_	_	V	_			
Sense pull-up resistor	R_{SQ}	20	30	45	kΩ	Internally connected to Q1			

¹⁾ Measured when the output voltage $V_{\rm Q}$ has dropped 100 mV from the nominal value.

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²⁾ Square wave at $V_{\rm I}$: 8 V to 18 V; f = 10 kHz; $t_{\rm r}$ = $t_{\rm f}$ \leq 100 ns.

³⁾ $V_{\rm Q2}$ connected to ADJ2.



Application Information

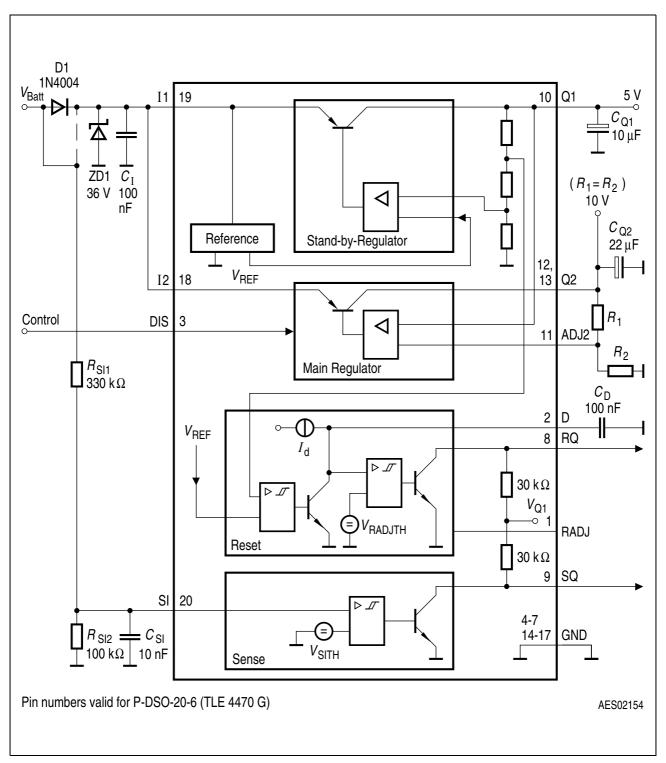


Figure 3 Application Circuit



Input, Output

The input capacitor $C_{\rm I}$ is necessary for compensating line influences. Using a resistor of approx. 1 Ω in series with $C_{\rm I}$, the LC circuit of input inductivity and input capacitance can be damped. To stabilize the regulation circuits of the stand-by and main regulator, output capacitors $C_{\rm Q1}$ and $C_{\rm Q2}$ are necessary. Stability is guaranteed at values $C_{\rm Q1} \geq$ 6 $\mu \rm F$ and $C_{\rm Q2} \geq$ 10 $\mu \rm F$, both with an ESR \leq 10 Ω within the operating temperature range.

For the TLE 4470 G (PG-DSO-20) the output voltage $V_{\rm Q2}$ of the main regulator can be adjusted to 5 V \leq $V_{\rm Q2,nom} \leq$ 20 V by connecting an external voltage divider to the voltage adjust pin ADJ2. For $V_{\rm Q2}$ = 5 V the voltage adjust pin has to be connected directly to the main output.

For calculating $V_{\rm O2}$ or R_1 and R_2 respectively the following equations can be used:

$$V_{O2} = V_{O1} \times (1 + R_1 / R_2) \tag{1}$$

or

$$R_1 = R_2 \times (V_{O2} / V_{O1} - 1) \tag{2}$$

Disable

The main regulator of the TLE 4470 can be switched OFF by a voltage above 2.3 V at pin DIS. Reducing this voltage below 1.4 V will switch ON the main regulator again.

Reset Timing

The power-on reset delay time is defined by the charging time of an external capacitor C_D which can be calculated as follows:

$$C_{\rm D} = (\Delta t \times I_{\rm D,c}) / \Delta V \tag{3}$$

Definitions:

- C_D = delay capacitor
- $\Delta t = \text{reset delay time}$
- $I_{D,c}$ = charge current, typical 5 μ A
- $\Delta V = V_{\text{DH}}$, typical 1.8 V
- V_{DU} = upper delay switching threshold at C_{D} for reset delay time

The reset reaction time $t_{\rm rr}$ is the time it takes the voltage regulator to set the reset out LOW after the output voltage has dropped below the reset threshold. It is typically 2 μ s for delay capacitor of 100 nF. For other values for $C_{\rm D}$ the reaction time can be estimated using the following equation:

$$t_{\rm rr} \approx 20 \text{ s/F} \times C_{\rm D}$$
 (4)



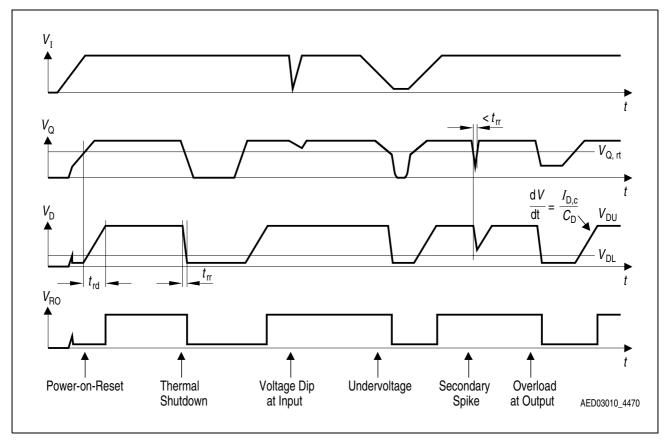


Figure 4 Reset Timing

Reset Switching Threshold

The internally set reset threshold is 4.65 V. When using the TLE 4470 G (PG-DSO-20) this threshold can be adjusted to 3.5 V < $V_{\rm Q,\,rt}$ < 4.6 V by connecting an external voltage divider to pin RADJ. If this pin is not needed, it can be left open or even better connected to GND.

$$R_1 = R_2 \times (V_{Q, rt} - V_{ref}) / V_{ref} \text{ or } V_{Q, rt} = V_{ref} (1 + R_1 / R_2)$$
 (5)

Definitions:

- $V_{O, rt}$ = Reset threshold
- $V_{\text{ref}} = \text{comparator reference voltage, typical 1.35 V}$ (Reset adjust input current $\approx 50 \text{ nA}$)

The reset output pin is internally connected to the stand-by output Q1 via a 30 k Ω pull-up resistor. The reset LOW signal at pin RQ is guaranteed down to an output voltage $V_{\rm Q1}$ of 1 V typical.



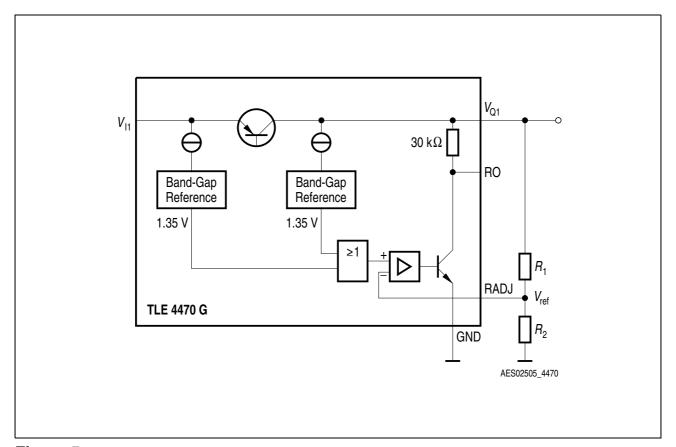


Figure 5

Early Warning

The early warning function compares a voltage defined by the user to an internal reference voltage. Therefore the voltage to be supervised has to be scaled down by an external voltage divider in order to compare it to internal sense threshold (reference voltage) which is typically 1.35 V. The sense out pin is set to low when the user defined voltage falls below this threshold.

A typical example where this circuit can be used is to supervise the input voltage $V_{\rm I}$ to give the microprocessor a prewarning of a low battery condition.

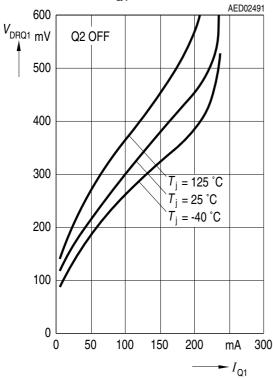
Calculation of the voltage divider can be easily done since the sense input current can be neglected. The equations needed for calculation are identical to the previously given ones.

To minimize transient influences the use of a capacitor in parallel to R_2 is recommended. Like the reset output pin, the sense out pin SQ is internally connected to the stand-by output Q1 via a 30 k Ω pull-up resistor. The sense out LOW signal at pin SQ is generated down to an input voltage V_{11} of 3 V typical.

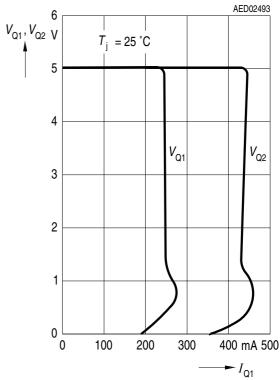


Typical Performance Characteristics

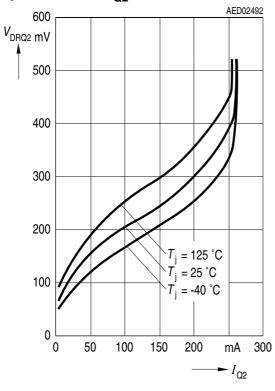
Drop Voltage V_{DRQ1} versus Output Current I_{Q1}



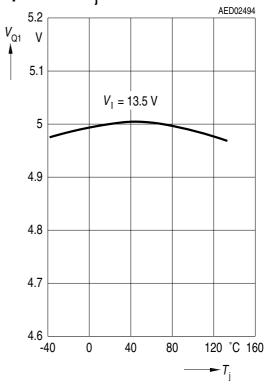
Output Voltage $V_{\mathrm{Q1}},\,V_{\mathrm{Q2}}$ versus Output Current I_{Q1}



Drop Voltage V_{DRQ2} versus Output Current I_{Q2}

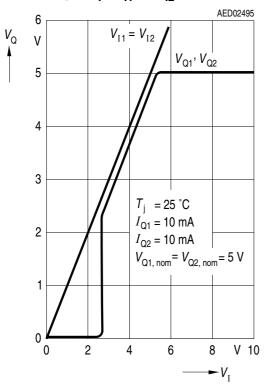


Output Voltage V_{Q1} versus Temperature T_{i}

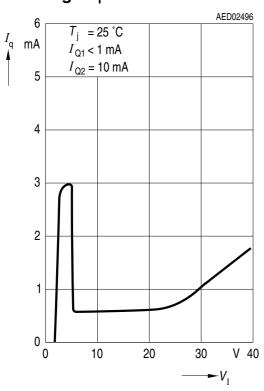




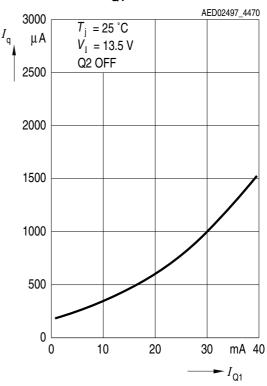
Output Voltage $V_{\rm Q1},\,V_{\rm Q2}$ versus Input Voltage $V_{\rm I}\,(V_{\rm I1}=V_{\rm I2})$



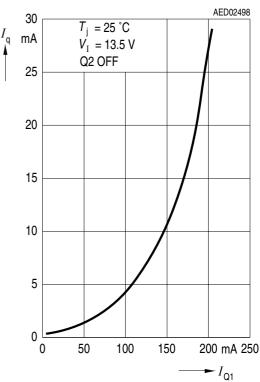
Current Consumption $I_{\rm q}$ versus Input Voltage $V_{\rm I}$



Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q1}$ (low load)

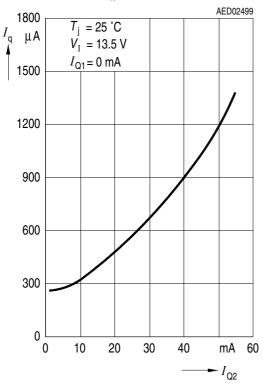


Current Consumption I_q versus Output Current I_{Q1} (high load)

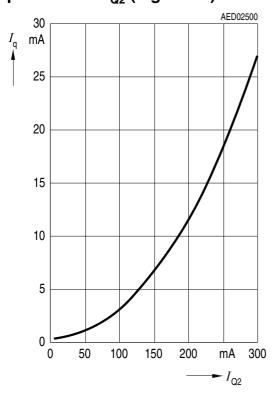




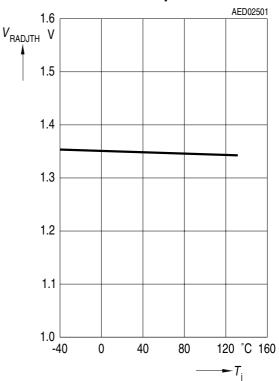
Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q2}$ (low load)



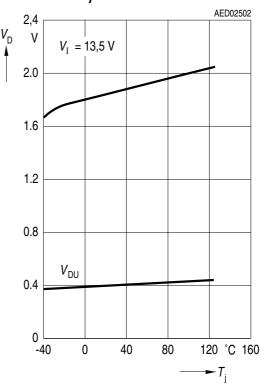
Current Consumption I_q versus Output Current I_{Q2} (high load)



Reset Adjust Threshold V_{RADJTH} versus Temperature T_{i}

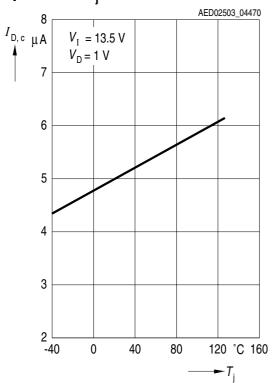


Switching Voltage $V_{\mathrm{DU}},\,V_{\mathrm{DL}}$ versus Temperature T_{i}

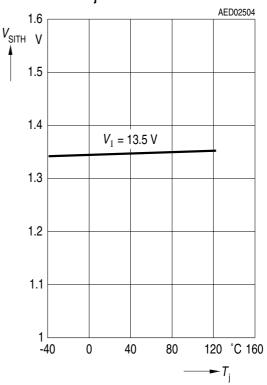




Charge Current $I_{\mathrm{D,c}}$ versus Temperature T_{j}



Sense Threshold $V_{\rm SITH}$ versus Temperature $T_{\rm i}$





Package Outlines

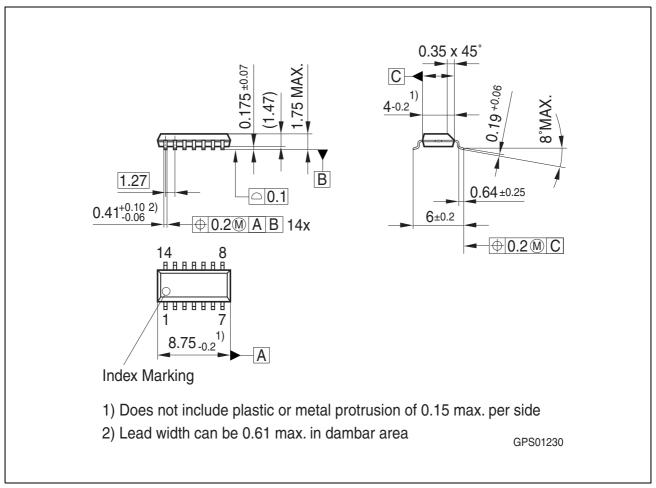


Figure 6 PG-DSO-14 (Plastic Green Dual Small Outline)

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": http://www.infineon.com/packages.

SMD = Surface Mounted Device

Dimensions in mm



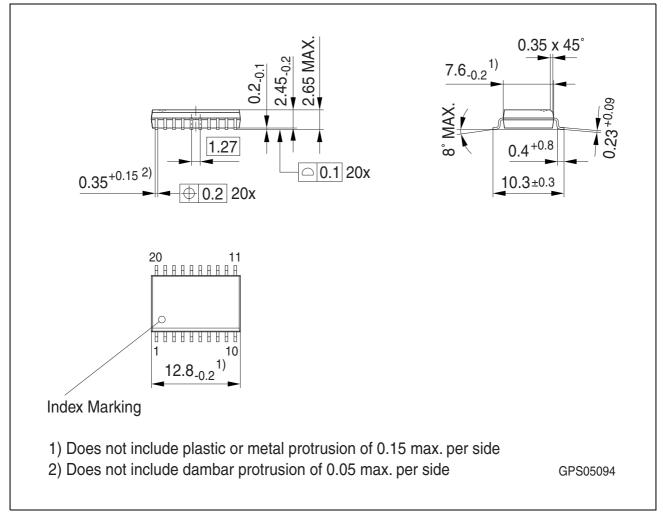


Figure 7 PG-DSO-20 (Plastic Green Dual Small Outline)

Green Product (RoHS compliant)

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SMD = Surface Mounted Device

Dimensions in mm



Revision History

Version	Date	Changes
Rev. 1.2	2008-03-20	Initial version of RoHS-compliant derivate of TLE 4470 Page 1: AEC certified statement added Page 1 and Page 21f: RoHS compliance statement and Green product feature added Page 1 and Page 21f: Package changed to RoHS compliant version Legal Disclaimer updated

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